

MAINTENANCE MANUAL

FOR

RECEIVER FRONT END MODULE

19D902782G5

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DESCRIPTION

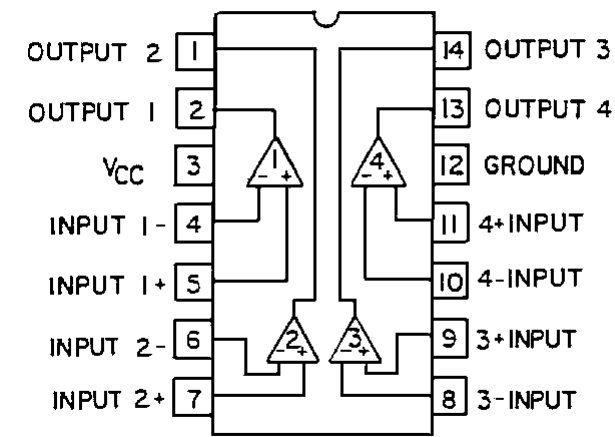
The Receiver Front End (RXFE) Module amplifies and converts the RF signal to the first IF signal of 70.2 MHz. This is a down conversion process using low side injection. The RXFE module is powered by a regulated 12 volts and draws about 260 mA. The RXFE printed wiring board contains the following functional circuits:

- Preselector Filter
- Preamplifier

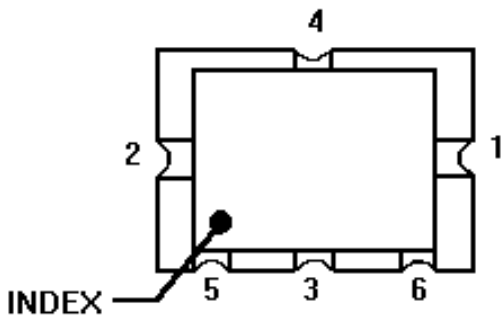
- Image Rejection Filter
- Injection Amplifier
- Injection Filter
- Double Balanced Mixer
- Fault Detector

All but the Fault Detector circuit in the RXFE module have 50 ohm impedance terminations.

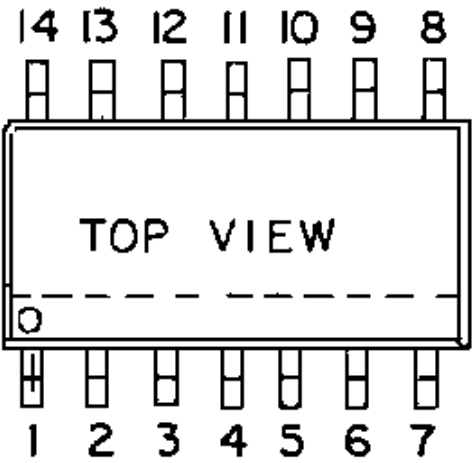
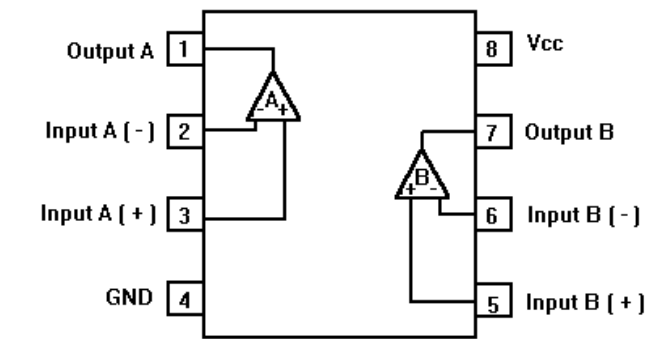
U1
19A704125P1
Quad Operational Amplifier



U30
RYTUA901201/1
Power Module



U40
19A704125P1
Quad Comparator



MAINTENANCE

TEST PROCEDURE

The RXFE module has to be tested for Noise Figure, Gain, Third Order Intercept Point, Isolation etc.. With proper current drawing of devices, Bandwidth and Conversion Gain the RXFE module will meet its specifications. The following are test procedures will verify proper Conversion Gain and current drain:

1. Supply 12 Vdc to pin 15A, B, C. (1C is ground.)
2. Inject the desired RF signal into RF IN at a level of -10 dBm.

3. Inject the desired local oscillator signal into LO IN at a level of 0 dBm (LO frequency = RF frequency- 70.2 MHz).
4. Measure the IF OUT power at 70.2 MHz, the ratio of RF IN to IF OUT is -2 dB ±1 dB.
5. Measure the current drawn by the RXFE module. Typical current drain is 260 mA.

TROUBLESHOOTING GUIDE

SYMPTOM	AREAS TO CHECK	READING (TYP.)
LOW CONVERSION GAIN	Check Vcc Preselector Loss Preamplifier Gain Image Rej. Filter Loss 1st Mixer Conversion Loss 1 L.O. Level (@ mixer L.O. port)	12 V 1.5 dB 9 dB 1.5 dB 6.0 dB +17 ±2 dBm
LED INDICATOR ON	Check Vc of Q1 Check Vc of Q20 and U20	10V 10V
IF FREQUENCY OFF	Check L.O. FREQUENCY	L.O. frequency = RF frequency - 70.2 MHz
LOW L.O. POWER*	Injection Amplifier Gain Injection Filter Loss	19 ±2 dB 2 dB

*NOTE: For troubleshooting the gain or loss, the RXFE needs to be under the normal operating condition:

- I2 Vdc supply.

• Inject L.O. power at a level of 0 dBm into LO IN (J3), (LO freq. = RF freq. - 70.2 MHz).

• Inject the desired RF signal at a level of -10 dBm into RF IN (J2).

• Terminate the IF OUT (J4) with a good 50 ohm impedance.

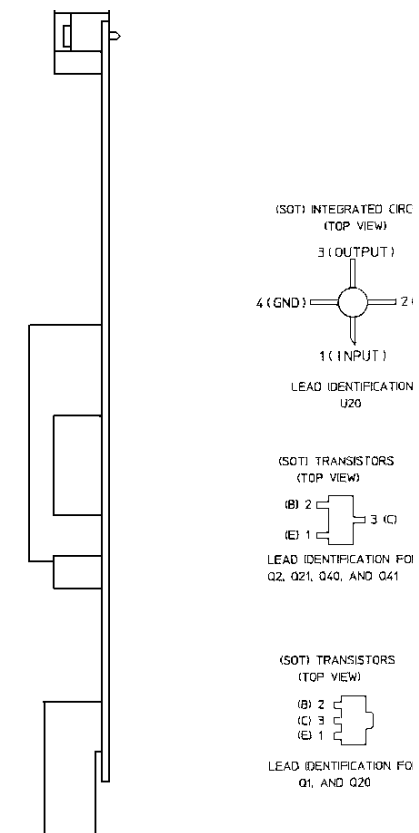
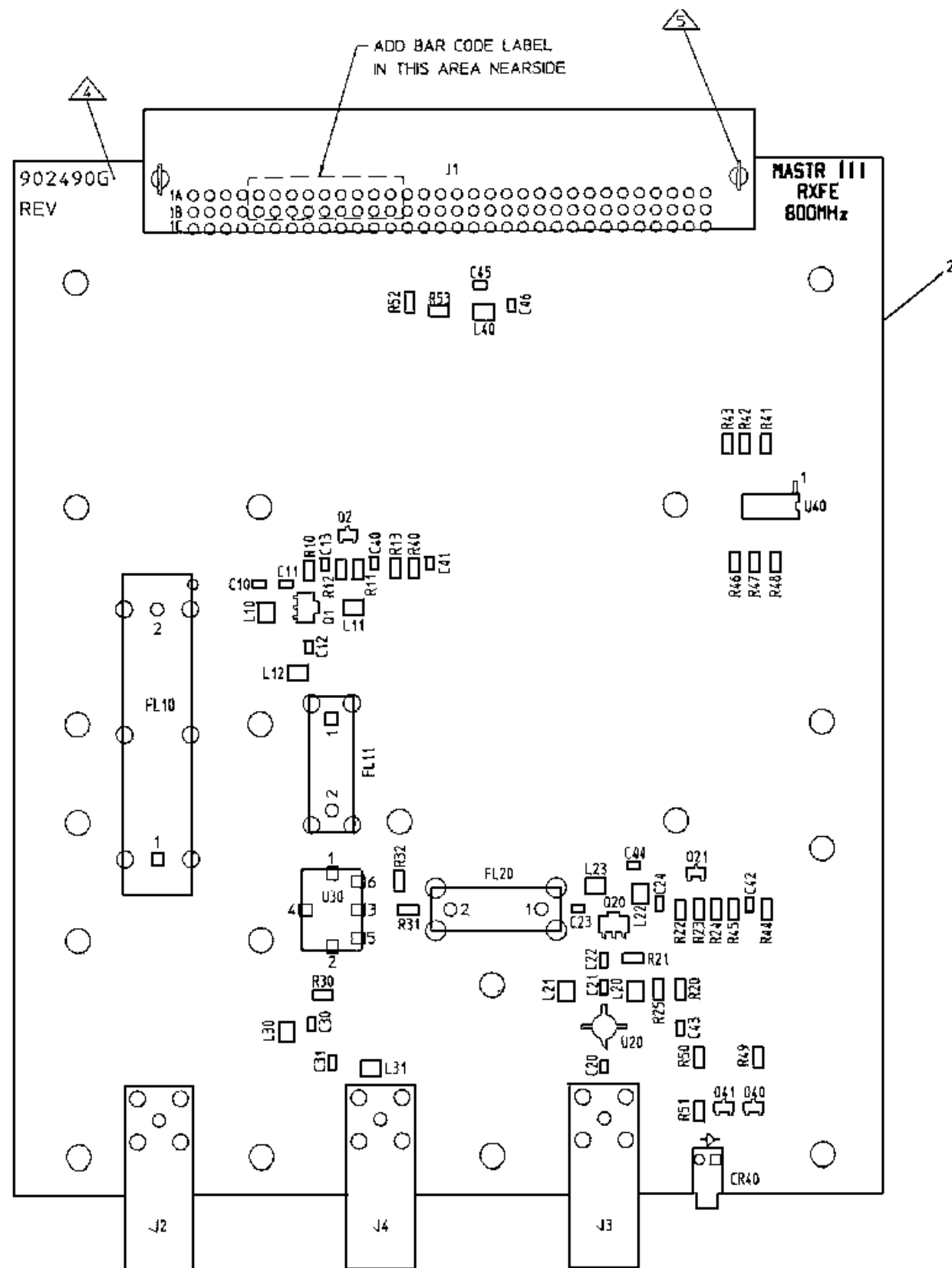
Use a Spectrum Analyzer and 50 ohm probe (with good RF grounding) to probe at the input and output of each stage to check its gain or loss (see schematic diagram).

RECEIVER FRONT END MODULE
19D902782G5
ISSUE 1

SYMBOL	PART NO.	DESCRIPTION
4	19D902555P1	Handle.
6	19A702381P506	Screw, thread forming: TORX No. M3.5-6 x 6.
7	19A702381P513	Screw, thread forming: TORX No M3.5-0.6 X.
11	19A702381P508	Screw, thread forming: No. 3.5-06 x 8.
RECEIVER FRONT END BOARD 19D902490G5		
----- CAPACITORS -----		
C10	19A702061P12	Ceramic: 8.2 pF 0.5 pF, 50 VDCW, temp coef 0 ±60 PPM.
C11	19A702061P10	Ceramic: 5.6 pF 0.5 pF, 50 VDCW, temp coef 0 ±60 PPM.
C12	19A702061P45	Ceramic: 47 pF 0.5 pF, 50 VDCW, temp coef 0 ±30 PPM.
C13	19A702052P14	Ceramic: 0.01 µF ±10%, 50 VDCW.
C20 and C21	19A702061P45	Ceramic: 47 pF 0.5 pF, 50 VDCW, temp coef 0 ±30 PPM.
C22	19A702061P8	Ceramic: 3.9 pF 0.5 pF, 50 VDCW, temp coef 0 ±120 PPM.
C23	19A702061P12	Ceramic: 8.2 pF 0.5 pF, 50 VDCW, temp coef 0 ±60 PPM.
C24	19A702052P14	Ceramic: 0.01 µF ±10%, 50 VDCW.
C30 and C31	19A702061P49	Ceramic: 56 pF ±5 %, 50 VDCW.
C40 thru C46	19A702052P14	Ceramic: Ceramic; 0.01 µF ±10%, 50 VDCW.
----- DIODES -----		
CR1	344A3062P1	Diode, Schottky.
CR40	19A703595P10	Diode, Optoelectric: Red; sim to HP HLMP-1301-010.
----- FILTERS -----		
FL10	RTNUA20201/1	Ceramic Bandpass.
FL11	19A704888P5	RF Filter: 806-825 MHz.
FL20	19A705767P1	Bandpass.
----- JACKS -----		
J1	19B801587P7	Connector, DIN: 96 male contacts, right angle mounting; sim to AMP 650887-1.
J2 thru J4	19A115938P24	Connector, receptacle.
----- INDUCTORS -----		
L10	344A4540P100	Inductor: 10.6 nH.
L11	19A705470P13	Coil, Fixed: 0.1 µH.
L12	344A4540P150	Inductor: 16.7 nH.
L20	19A705470P13	Coil, Fixed: 0.1 µH.
L21	19A705470P1	Coil, Fixed: 10 nH; sim to Toko 380NB-10nM.
L22	19A705470P13	Coil, Fixed: 0.1 µH ±20%; sim to Toko 380NB-R10M.
L23	19A705470P7	Coil, Fixed: 33 nH ±20%; sim to Toko 380NB-33nM.

*COMPONENTS, ADDED OR DELETED OR CHANGED BY PRODUCTION CHANGES

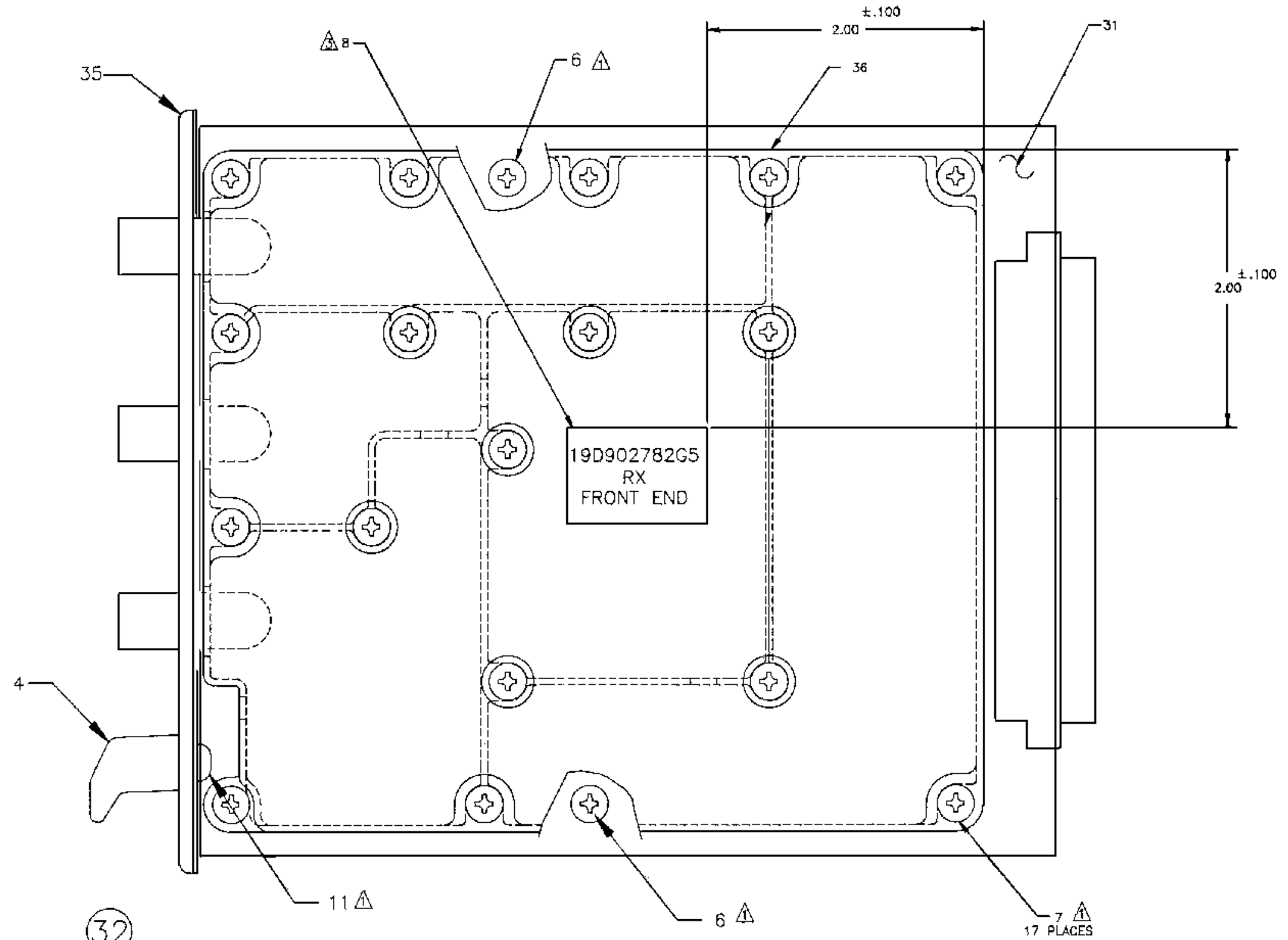
SYMBOL	PART NO.	DESCRIPTION
L30 and L31	19A705470P13	Coil, Fixed: 0.1 µH ±20%; sim to Toko 380NB-R10M.
L40	19A705470P16	Coil, Fixed: 0.18 µH; sim to Toko 380NB-R18M.
----- TRANSISTORS -----		
Q1	344A3058P1	Silicon, NPN.
Q2	19A700059P2	Silicon, PNP; sim to MMBT3906, low profile.
Q20	344A3058P1	Silicon, NPN.
Q21	19A700059P2	Silicon, PNP; sim to MMBT3906, low profile.
Q40 and Q41	19A700076P2	Silicon, NPN; sim to MMBT3904, low profile.
----- RESISTORS -----		
R10	19B80060°7P183	Metal Film: 18K ohms ±5%, 1/8w.
R11	19B80060°7P102	Metal Film: 1K ohms ±5%, 1/8w.
R12	19B80060°7P331	Metal Film: 330 ohms ±5%, 1/8w.
R13 and R20	19B80060°7P270	Metal Film: 27 ohms ±5%, 1/8w.
R21	19B80060°7P183	Metal Film: 18K ohms ±5%, 1/8w.
R22	19B80060°7P102	Metal Film: 1K ohms ±5%, 1/8w.
R23	19B80060°7P331	Metal Film: 330 ohms ±5%, 1/8w.
R24	19B80060°7P270	Metal Film: 27 ohms ±5%, 1/8w.
R25 and R30	19B80060°7P510	Metal Film: 51 ohms ±5%, 1/8w.
R31	19B80060°7P100	Metal Film: 10 ohms ±5%, 1/8w.
R32	19B80060°7P201	Metal Film: 200 ohms ±5%, 1/8w.
R40	19B80060°7P103	Metal Film: 10K ohms ±5%, 1/8w.
R41	19B80060°7P562	Metal Film: 5.6K ohms ±5%, 1/8w.
R42	19B80060°7P183	Metal Film: 18K ohms ±5%, 1/8w.
R43	19B80060°7P333	Metal Film: 33K ohms ±5%, 1/8w.
R44 and R45	19B80060°7P103	Metal Film: 10K ohms ±5%, 1/8w.
R46	19B80060°7P822	Metal Film: 8.2K ohms ±5%, 1/8w.
R47 and R48	19B80060°7P333	Metal Film: 33K ohms ±5%, 1/8w.
R49	19B80060°7P104	Metal Film: 100K ohms ±5%, 1/8w.
R50	19B80060°7P273	Metal Film: 27K ohms ±5%, 1/8w.
R51	19B80060°7P102	Metal Film: 1K ohms ±5%, 1/8w.
R52	19B800607P103	Metal Film: 10K ohms ±5%, 1/8w.
R53	19B800607P682	Metal Film: 6.8K ohms ±5%, 1/8w.
-- INTEGRATED CIRCUITS --		
U1	19A704125P1	Linear: Quad Comparator; sim to LM339D.
U20	344A3907P1	MMIC: sim to Avantek MSA-1105.
U30	RYTUA901201/1	Power Module: MOS FET.
U40	19A704125P1	Linear: Quad Comparator; sim to LM339D.



RECEIVER FRONT END PWB

19D902490G5

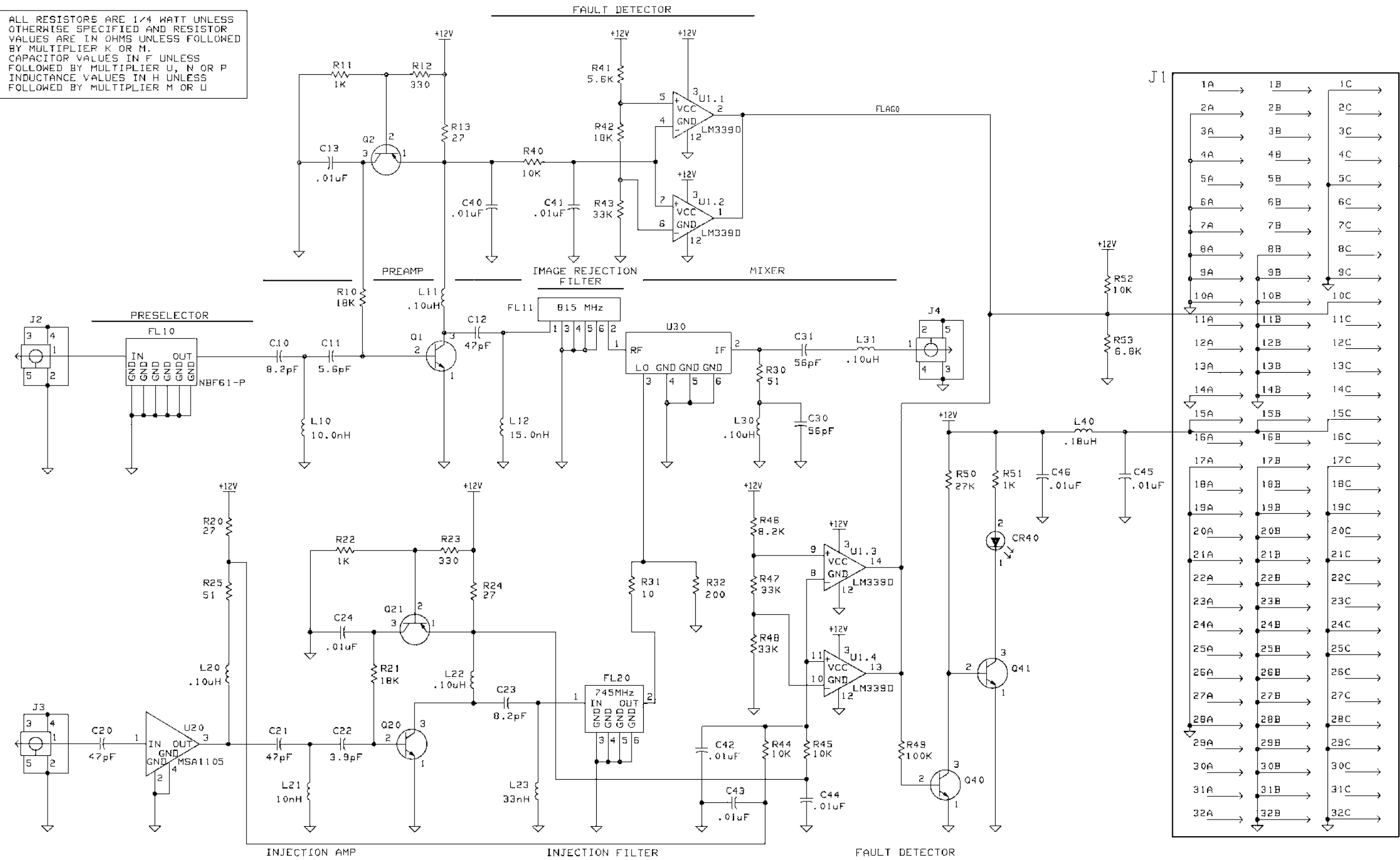
(19D902490, Sh. 6, Rev. 1)



(19D902782, Sh. 3, Rev. 1)

**⚠ TORQUE SCREWS, ITEMS 6 AND 7, TO 15.5 ±1.3 INCH POUNDS.
TORQUE SCREWS, ITEM 11 , TO 20 ±1.3 INCH POUNDS.**

ALL RESISTORS ARE 1/4 WATT UNLESS OTHERWISE SPECIFIED AND RESISTOR VALUES ARE IN OHMS UNLESS FOLLOWED BY MULTIPLIER K OR M.
CAPACITOR VALUES IN F UNLESS FOLLOWED BY MULTIPLIER U, N OR P
INDUCTANCE VALUES IN H UNLESS FOLLOWED BY MULTIPLIER M OR U



RECEIVER FRONT END MODULE

19D902782G5

(19D904935, Sh. 1, Rev. 4)